

Accepted Manuscript

Soft thermal nanoimprint of PMMA doped with upconverter nanoparticles

Hubert Hauser, Barbara Herter, Clarissa L.M. Hofmann, Oliver Höhn, Volker Kübler, Stefan Fischer, Sebastian Wolf, Stefan Fasold, Frank C.J.M. van Veggel, Jan Christoph Goldschmidt, Benedikt Bläsi



PII: S0167-9317(17)30368-4
DOI: doi:[10.1016/j.mee.2017.11.004](https://doi.org/10.1016/j.mee.2017.11.004)
Reference: MEE 10655
To appear in: *Microelectronic Engineering*
Received date: 20 July 2017
Revised date: 22 September 2017
Accepted date: 3 November 2017

Please cite this article as: Hubert Hauser, Barbara Herter, Clarissa L.M. Hofmann, Oliver Höhn, Volker Kübler, Stefan Fischer, Sebastian Wolf, Stefan Fasold, Frank C.J.M. van Veggel, Jan Christoph Goldschmidt, Benedikt Bläsi, Soft thermal nanoimprint of PMMA doped with upconverter nanoparticles. The address for the corresponding author was captured as affiliation for all authors. Please check if appropriate. Mee(2017), doi:[10.1016/j.mee.2017.11.004](https://doi.org/10.1016/j.mee.2017.11.004)

This is a PDF file of an unedited manuscript that has been accepted for publication. As a service to our customers we are providing this early version of the manuscript. The manuscript will undergo copyediting, typesetting, and review of the resulting proof before it is published in its final form. Please note that during the production process errors may be discovered which could affect the content, and all legal disclaimers that apply to the journal pertain.

Soft thermal nanoimprint of PMMA doped with upconverter nanoparticles

Hubert Hauser¹, Barbara Herter¹, Clarissa L. M. Hofmann^{1,2}, Oliver Höhn¹, Volker Kübler¹, Stefan Fischer³, Sebastian Wolf¹, Stefan Fasold⁴, Frank C.J.M. van Veggel⁵, Jan Christoph Goldschmidt¹, Benedikt Bläsi¹

¹Fraunhofer Institute for Solar Energy Systems ISE, Heidenhofstraße 2, 79110 Freiburg, Germany

²Institute of Microstructure Technology (IMT), Karlsruhe Institute of Technology, Hermann-von-Helmholtz-Platz 1, 76344 Eggenstein-Leopoldshafen, Germany

³Department of Materials Science and Engineering, Stanford University, Stanford, California 94305, USA

⁴Institute of Applied Physics, Abbe Center of Photonics, Friedrich-Schiller-Universität Jena, Max-Wien-Platz 1, 07743 Jena, Germany

⁵Department of Chemistry, University of Victoria, Victoria, British Columbia, Canada V8W 2Y2 and Centre for Advanced Materials and Related Technologies (CAMTEC)

ABSTRACT

Upconversion of low-energy photons into higher energy photons is a non-linear effect that can be strongly enhanced by increasing the intensity of impinging light. Such an enhanced intensity can also be achieved by near-field optical effects in photonic structures. In this paper, we investigate photonic structures in the form of linear gratings with varying periods realized in poly-methyl-methacrylate (PMMA) layers using soft stamps in a thermal nanoimprint process. Master structures were fabricated using e-beam lithography and reactive ion etching in silicon. These master structures were replicated into bi-layer polydimethylsiloxane (PDMS) stamps. PMMA layers with embedded β -NaYF₄: 25% Er³⁺ upconverter nanoparticles were applied to glass substrates using spin coating. The PDMS stamps were used to imprint the PMMA layer with very accurate pattern fidelity. The upconversion luminescence around 980 nm was enhanced more than three times by the photonic structure under 1523 nm laser excitation with 0.43 ± 0.02 W/cm² irradiance, in comparison to a reference sample containing the same amount of upconverter material.

Keywords: Upconversion, nanoimprint lithography, hot embossing, PDMS, soft lithography, photonic structures, solar cells.

1. INTRODUCTION

Upconversion – the emission of one high-energy photon after the absorption of two or more low-energy photons – is relevant for many applications including bioimaging and theranostics [1–4], security [5] and photovoltaics [6–9]. In photovoltaics, upconversion offers the potential for significant efficiency gains by converting photons with energies below the absorption threshold into photons with sufficient energy for utilization, pushing the maximum achievable efficiency for a silicon solar cell from 30% to 40.2% [7]. For silicon photovoltaics, especially trivalent erbium (Er³⁺) features conveniently spaced energy levels that allow for upconversion of photons with wavelengths

Download English Version:

<https://daneshyari.com/en/article/6942690>

Download Persian Version:

<https://daneshyari.com/article/6942690>

[Daneshyari.com](https://daneshyari.com)